2SC4517/4517A

Silicon NPN Triple Diffused Planar Transistor (High Voltage Switchihg Transistor)

Application: Switching Regulator and General Purpose

Absolute maximum ratings (Ta=25°C)						
Symbol	2SC4517	2SC4517A	Unit			
Vсво	900	1000	V			
VCEO	5	V				
VEBO		V				
Ic	3(P	А				
Ів	1	Α				
Pc	30(Tc=25°C)		W			
Tj	1	°C				
Tstg	–55 t	°C				

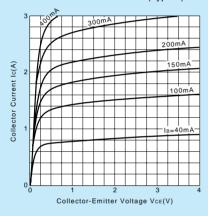
Electrica	al Characteristics		(Ia	=25°C)	
Symbol	Conditions	2SC4517	2SC4517A	Unit	
Ісво	Vcb=800V	100max		μΑ	
I EBO	VEB=7V	100max		μΑ	
V(BR)CEO	Ic=10mA	550min		V	
hfe	Vce=4V, Ic=1A	10 to 30			
Vce(sat)	Ic=1A, IB=0.2A	0.5max		V	
VBE(sat)	Ic=1A, IB=0.2A	1.2max		V	
fт	Vce=12V, Ie=-0.25A	6	typ	MHz	
Сов	VcB=10V, f=1MHz	35	typ	pF	

External Dimensions FM20(TO220F)

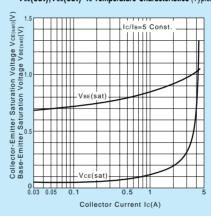
T .	:1	Curitahina	Characteristics	10	C:441	
	ypicai	Switching	Characteristics	(Common	Ellillitel)	,

				,					
Vcc (V)	RL (Ω)	Ic (A)	V _{BB1} (V)	VBB2 (V)	Iв1 (A)	IB2 (A)	ton (µs)	tstg (µs)	tf (µs)
250	250	1	10	-5	0.15	-0.45	0.7max	4max	0.5max



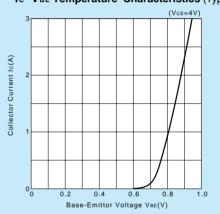


VcE(sat), VBE(sat)-Ic Temperature Characteristics (Typical)

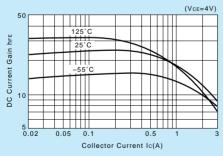


Ic-VBE Temperature Characteristics (Typical)

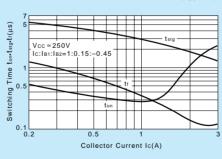
Weight: Approx 2.0g a. Type No. b. Lot No.



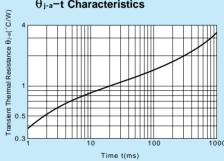
hfe-Ic Temperature Characteristics (Typical)



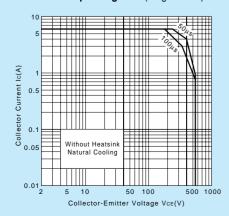
ton • tstg • tf-Ic Characteristics (Typical)



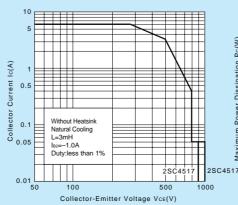
θ_{j-a}-t Characteristics



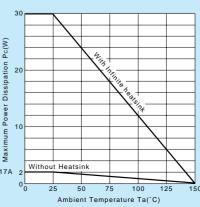
Safe Operating Area (Single Pulse)



Reverse Bias Safe Operating Area



Pc-Ta Derating



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